

Supporting information

Optical properties and carrier dynamics in Co-doped ZnO nanorods

Aswathi K. Sivan^{*a}, Alejandro Galán-González^{b,c}, Lorenzo Di Mario^d, Nicolas Tappy^e, Javier Hernández-Ferrer^f, Daniele Catone^d, Stefano Turchini^d, Ana M. Benito^f, Wolfgang K. Maser^f, Simon Escobar Steinvall^e, Anna Fontcuberta i Morral^{e,g}, Andrew Gallant^b, Dagou A. Zeze^{b,h}, Del Atkinson^c, and Faustino Martelli^{*a}

^a*Istituto per la Microelettronica e i Microsistemi (IMM), CNR, I-00133, Rome, Italy*

^b*Department of Engineering, Durham University, South Rd, Durham, DH1 3LE, UK*

^c*Department of Physics, Durham University, South Rd, Durham, DH1 3LE, UK*

^d *Istituto di Struttura della Materia-CNR (ISM-CNR), Division of Ultrafast Processes in Materials (FLASHit), Area della Ricerca di Roma 2 Tor Vergata, 00133 Rome, Italy.*

^e*Laboratoire des Matériaux Semiconducteurs, Institute of Materials, Faculty of Engineering, École Polytechnique Fédérale de Lausanne, 1015 Lausanne, Switzerland*

^f*Instituto de Carboquímica (ICB-CSIC), C/ Miguel Luesma Castán 4, 50018 Zaragoza, Spain*

^g*Institute of Physics, Faculty of Basic Sciences, École Polytechnique Fédérale de Lausanne, Lausanne, Switzerland*

^h*ITMO University, St. Petersburg, 197101, Russia*

[*faustino.martelli@cnr.it](mailto:faustino.martelli@cnr.it) [*aswathi.sivan@artov.imm.cnr.it](mailto:aswathi.sivan@artov.imm.cnr.it)

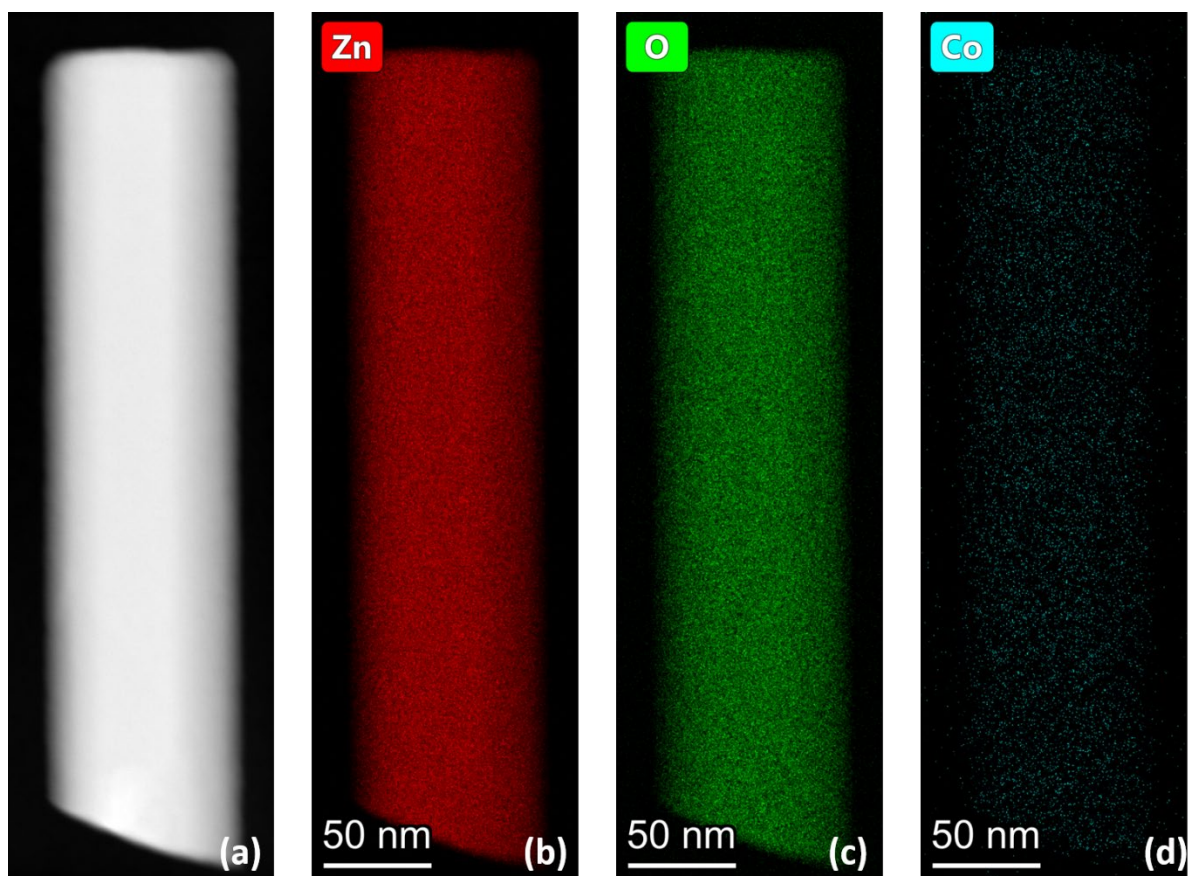


Figure S 1. (a) HAADF image of a transferred ZnO NR grown on ITO; Elemental maps obtained through STEM-EDX showing distribution of (b)Zn; (c) O and (d) Co along the length of the NR.